NSN 5961-01-333-6199

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View Online at https://aerobasegroup.com/nsn/5961-01-333-6199

Inclosure Material:
Plastic
Overall Length:
Between 14.23 millimeters and 16.51 millimeters
Terminal Length:
Between 12.7 millimeters and 14.73 millimeters
Overall Height:
Between 3.56 millimeters and 4.82 millimeters
Overall Width:
Between 9.66 millimeters and 10.66 millimeters
Function For Which Designed:
Switching
End Application:
5865-01-188-3309 an/ulq-1 (v) 1 jammer system respo
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-220ab
Mounting Method:
Terminal and unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
80.0 breakdown voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
8.00 amperes source cutoff current
Power Rating Per Characteristic:
65.0 watts small-signal input power, common-collector absolute
Transfer Ratio:
15.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Terminal Type And Quantity:
3 pin
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

